Karl E Spear

List of Publications by Year in descending order

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759233 713466 1,770 24 12 21 citations h-index g-index papers 26 26 26 801 docs citations times ranked citing authors all docs

#	Article	IF	CITATIONS
1	Diamond-Ceramic Coating of the Future. Journal of the American Ceramic Society, 1989, 72, 171-191.	3.8	646
2	Growth mechanism of vapor-deposited diamond. Journal of Materials Research, 1988, 3, 133-140.	2.6	369
3	Oxidation Studies of Crystalline CVD Silicon Nitride. Journal of the Electrochemical Society, 1989, 136, 1527-1536.	2.9	199
4	Passive-Oxidation Kinetics of High-Purity Silicon Carbide from 800o to 1100oC. Journal of the American Ceramic Society, 1996, 79, 2897-2911.	3.8	127
5	Thermochemical Modeling of Oxide Glasses. Journal of the American Ceramic Society, 2002, 85, 2887-2894.	3.8	90
6	Thermodynamic Analysis of Silica Refractory Corrosion in Glass-Melting Furnaces. Journal of the Electrochemical Society, 2001, 148, B59.	2.9	66
7	Analysis of the Chemical Vapor Deposition of Titanium Diboride: I. Equilibrium Thermodynamic Analysis. Journal of the Electrochemical Society, 1977, 124, 786-790.	2.9	51
8	Thermochemical Modeling of Glass: Application to High-Level Nuclear Waste Glass. MRS Bulletin, 1999, 24, 37-44.	3.5	47
9	Thermodynamic Analysis of Alumina Refractory Corrosion by Sodium or Potassium Hydroxide in Glass Melting Furnaces. Journal of the Electrochemical Society, 2002, 149, B551.	2.9	28
10	Corrosion of Sic Materials in N2-H2-CO Gaseous Environments: I, Thermodynamics and Kinetics of Reactions. Journal of the American Ceramic Society, 1992, 75, 3257-3267.	3.8	24
11	Phase Behavior and Related Properties of Rare-Earth Borides. , 1976, , 91-159.		19
12	Isotopic Studies of Oxidation of Si3 N 4 and Si using SIMS. Journal of the Electrochemical Society, 1990, 137, 741-742.	2.9	17
13	Corrosion of SiC Mateials in N2-H2-CO Gaseous Environments: II, Durability and Mechanical Properties. Journal of the American Ceramic Society, 1992, 75, 3268-3277.	3.8	12
14	Oxidation Behavior of CVD and Single Crystal SiC at 1100°C. Journal of the Electrochemical Society, 1995, 142, L214-L216.	2.9	12
15	Assessment of the thermodynamic properties of vanadium silicides utilizing ternary phase equilibria. Journal of the Less Common Metals, 1978, 60, 185-193.	0.8	11
16	Oxygen poisoning of diamond film growth. Applied Physics Letters, 1993, 63, 2641-2643.	3.3	11
17	Formation of Active Carbon in Twin-Crucible Studies of Vanadium Carbonitride Solutions. Journal of the American Ceramic Society, 1969, 52, 257-262.	3.8	9
18	High-Temperature Reactivity., 1976,, 115-192.		9

#	Article	IF	CITATIONS
19	Chemical transport reactions. A relevant area of research. Journal of Chemical Education, 1972, 49, 81.	2.3	8
20	Predicting The Chemistry In Cvd Systems. Materials Research Society Symposia Proceedings, 1989, 168, 19.	0.1	8
21	Etching of Silicon Carbide Materials at Elevated Temperatures in a Nitrogen-Based Gas. Journal of the American Ceramic Society, 1991, 74, 457-459.	3.8	3
22	Discontinuous Phase Formation and Selective Attack of SiC Materials Exposed to Low Oxygen Partial Pressure Environments. NATO Advanced Study Institutes Series Series E, Applied Sciences, 1994, , 153-164.	0.2	3
23	Predicted Infrared Spectrum and X-Ray Diffraction Patterns for Diamond Polyiypes. Materials Research Society Symposia Proceedings, 1989, 162, 213.	0.1	1
24	Extension of the Modified Associate Species Thermochemical Model for High-Level Nuclear Waste: Inclusion of Chromia. Materials Research Society Symposia Proceedings, 2002, 757, II5.12.1.	0.1	0